(1) Gate (2) Collector

(3) Emitter



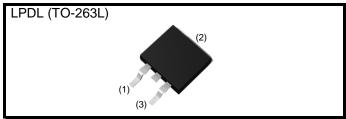
RGS60NL65HRBTL

650V 30A Field Stop Trench IGBT

V_{CES}	650V
I _C	30A
V _{CE(sat) (Typ.)}	1.65V
P _D	228W

Outline

●Inner Circuit



Features

- 1) Qualified to AEC-Q101
- 2) Low Collector Emitter Saturation Voltage
- 3) Short Circuit Withstand Time 8µs
- 4) Pb free Lead Plating; RoHS Compliant

●Packaging Specifications

(2)

T aona	ging opcomoduons			
	Packaging	Taping		
	Reel Size (mm)	330		
Typo	Tape Width (mm)	24		
Type	Basic Ordering Unit (pcs)	1,000		
	Packing Code	TL		
	Marking	RGS60NL65		

Application

Heater for Automotive

● Absolute Maximum Ratings (at T_C = 25°C unless otherwise specified)

Parameter		Symbol	Value	Unit
Collector - Emitter Voltage		V_{CES}	650	V
Gate - Emitter Voltage		V_{GES}	±30	V
Collector Current	T _C = 25°C	I _C	59	Α
Collector Current	T _C = 100°C	I _C	40	Α
Pulsed Collector Current		I _{CP} *1	90	Α
Power Dissipation	T _C = 25°C	P _D	228	W
	T _C = 100°C	P _D	119	W
Operating Junction Temperature		T _j	-40 to +175	°C
Storage Temperature		T _{stg}	-55 to +175	°C

^{*1} Pulse width limited by $T_{\text{jmax.}}$

●Thermal Resistance

Doromotor	Symbol	Values			Unit
Parameter	Symbol	Min.	Тур.	Max.	Offic
Thermal Resistance IGBT Junction - Case	$R_{\theta(j-c)}$	-	-	0.63	°C/W

●IGBT Electrical Characteristics (at T_j = 25°C unless otherwise specified)

Parameter	Symbol	Conditions		Unit		
Farameter	Symbol	Conditions	Min.	Тур.	Max.	Offic
Collector - Emitter Breakdown Voltage	BV _{CES}	$I_{C} = 10 \mu A, V_{GE} = 0 V$	650	-	-	V
		$V_{CE} = 650V, V_{GE} = 0V,$				
Collector Cut - off Current	I _{CES}	$T_j = 25^{\circ}C$	-	-	10	μΑ
		Tj = 175°C	-	0.1	-	mA
Gate - Emitter Leakage Current	I _{GES}	$V_{GE} = \pm 30V, V_{CE} = 0V$	ı	ı	±200	nA
Gate - Emitter Threshold Voltage	$V_{GE(th)}$	$V_{CE} = 5V, I_{C} = 1.5mA$	5.0	6.0	7.0	V
		$I_C = 30A, V_{GE} = 15V,$				
Collector - Emitter Saturation Voltage	V _{CE(sat)}	T _j = 25°C T _i = 175°C	-	1.65	2.10	V
		T _j = 175°C	-	2.15	-	V

●IGBT Electrical Characteristics (at T_j = 25°C unless otherwise specified)

Doromator	Symbol	Conditions		Unit		
Parameter			Min.	Тур.	Max.	Offic
Input Capacitance	C_{ies}	$V_{CE} = 30V$,	-	980	-	
Output Capacitance	C _{oes}	$V_{GE} = 0V$,	-	80	-	pF
Reverse transfer Capacitance	C_{res}	f = 1MHz	ı	13	ı	
Total Gate Charge	Q_g	V _{CE} = 400V,	-	36	-	
Gate - Emitter Charge	Q_ge	$I_{\rm C} = 30A$,	-	10	-	nC
Gate - Collector Charge	Q_{gc}	V _{GE} = 15V	-	15	-	
Turn - on Delay Time	t _{d(on)}		-	31	-	ns
Rise Time	t _r	$I_C = 30A, V_{CC} = 400V,$ $V_{GE} = 15V, R_G = 10\Omega,$	-	13	-	
Turn - off Delay Time	$t_{d(off)}$	$T_i = 25^{\circ}C$	-	94	-	
Fall Time	t _f	Inductive Load	-	91	-	
Turn - on Switching Loss	E _{on}	*E _{on} include diode reverse recovery	-	0.65	-	mJ
Turn - off Switching Loss	E_{off}	•	-	0.79	-	
Turn - on Delay Time	t _{d(on)}		-	31	-	
Rise Time	t _r	$I_C = 30A, V_{CC} = 400V,$ $V_{GE} = 15V, R_G = 10\Omega,$	-	15	-	ns
Turn - off Delay Time	$t_{d(off)}$	$T_i = 175^{\circ}C$	-	111	-	
Fall Time	t _f	Inductive Load	-	138	-	
Turn - on Switching Loss	E _{on}	*E _{on} include diode reverse recovery	-	0.73	-	
Turn - off Switching Loss	E _{off}		-	1.03	-	mJ
		$I_C = 90A, V_{CC} = 520V,$				-
Reverse Bias Safe Operating Area	RBSOA	$V_P = 650V, V_{GE} = 15V,$	FULL SQUARE			
date operating Area		$R_G = 50\Omega, T_j = 175^{\circ}C$				
Short Circuit Withstand Time	t _{sc}	$V_{CC} \le 360V$, $V_{GE} = 15V$, $T_j = 25^{\circ}C$	8	-	-	μs
Short Circuit Withstand Time	t _{sc} *2	$V_{CC} \le 360V$, $V_{GE} = 15V$, $T_j = 150$ °C	6	-	-	μs

*2 Design assurance without measurement

Electrical Characteristic Curves

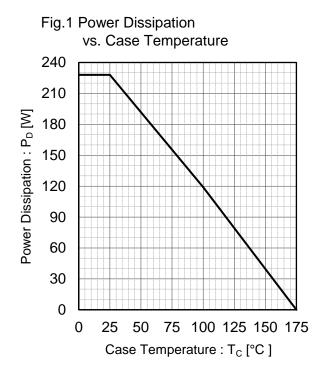


Fig.2 Collector Current vs. Case Temperature 70 60 Collector Current : I_C [A] 50 40 30 20 10 $T_i \leq 175^{\circ}C$ 0 25 50 75 100 125 150 175 0 Case Temperature : T_C [°C]

Fig.3 Forward Bias Safe Operating Area

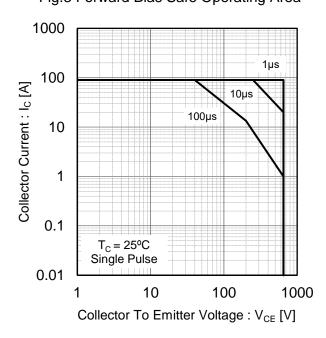
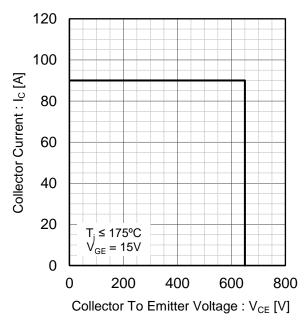


Fig.4 Reverse Bias Safe Operating Area



• Electrical Characteristic Curves

Fig.5 Typical Output Characteristics

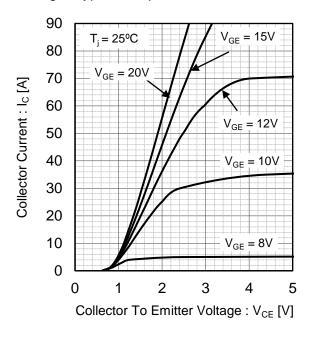


Fig.6 Typical Output Characteristics

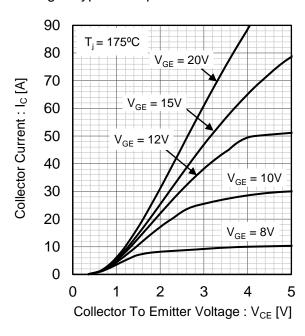


Fig.7 Typical Transfer Characteristics

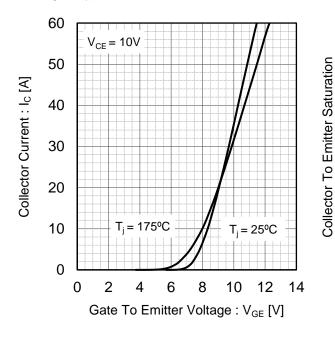
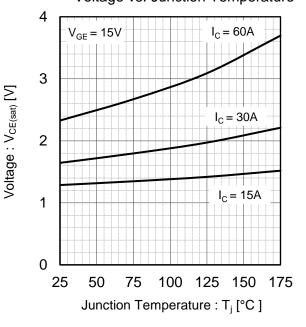


Fig.8 Typical Collector To Emitter Saturation Voltage vs. Junction Temperature



Collector To Emitter Saturation

• Electrical Characteristic Curves

Fig.9 Typical Collector To Emitter Saturation Voltage vs. Gate To Emitter Voltage

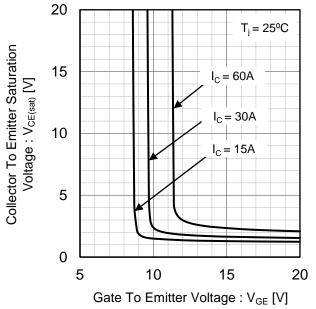


Fig.10 Typical Collector To Emitter Saturation Voltage vs. Gate To Emitter Voltage

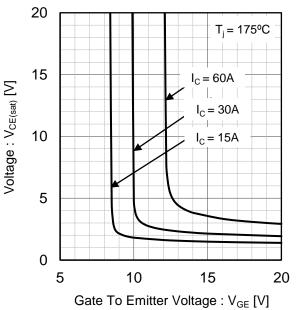


Fig.11 Typical Capacitance vs. Collector To Emitter Voltage

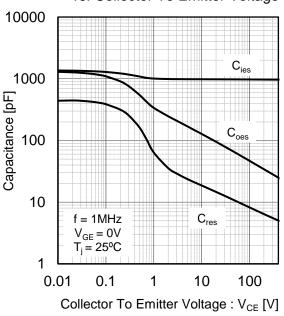
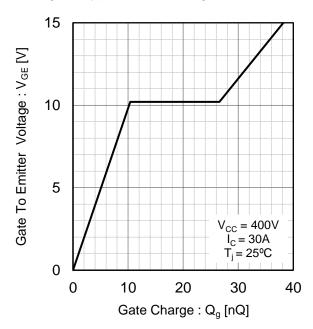
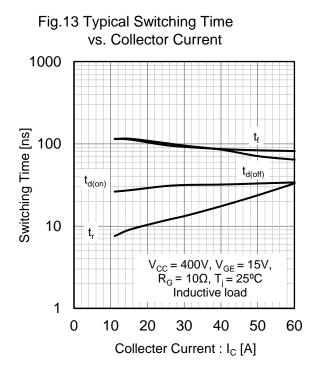


Fig.12 Typical Gate Charge



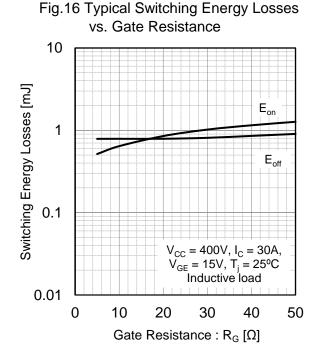
• Electrical Characteristic Curves



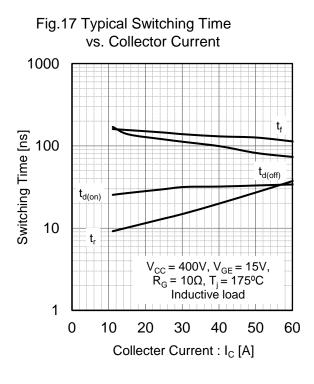
vs. Gate Resistance 1000 $t_{d(off)}$ Switching Time [ns] 100 $t_{d(on)}$ 10 V_{CC} = 400V, I_{C} = 30A, V_{GE} = 15V, T_{j} = 25°C Inductive load 1 0 10 20 30 40 50 Gate Resistance : $R_G[\Omega]$

Fig.14 Typical Switching Time

Fig.15 Typical Switching Energy Losses vs. Collector Current 10 Switching Energy Losses [mJ] 1 $\mathsf{E}_{\mathsf{off}}$ 0.1 Eon $V_{CC} = 400V, V_{GE} = 15V,$ $R_{G} = 10\Omega, T_{j} = 25^{\circ}C$ Inductive load 0.01 0 10 20 30 40 50 60 Collector Current : I_C [A]



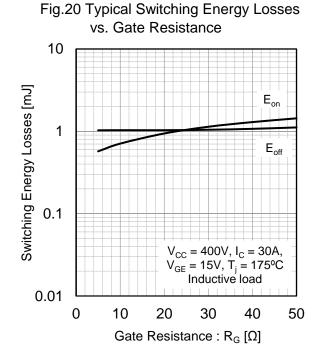
• Electrical Characteristic Curves



vs. Gate Resistance 1000 Switching Time [ns] 100 $t_{d(off)}$ $t_{d(on)}$ 10 $V_{CC} = 400V, I_C = 30A,$ $V_{GE} = 15V, T_j = 175^{\circ}C$ Inductive load 1 0 10 20 30 40 50 Gate Resistance : $R_G[\Omega]$

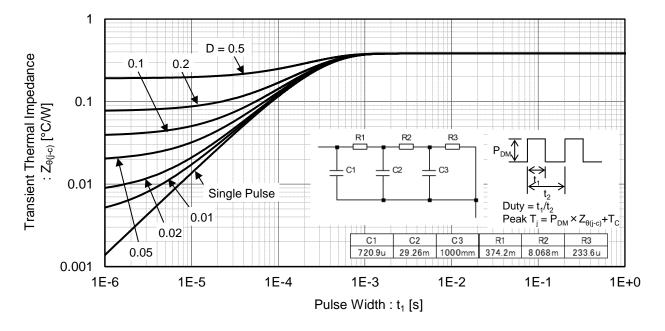
Fig.18 Typical Switching Time

Fig.19 Typical Switching Energy Losses vs. Collector Current 10 Switching Energy Losses [mJ] 1 $\mathsf{E}_{\mathsf{off}}$ E_{on} 0.1 V_{CC} = 400V, V_{GE} = 15V, R_G = 10 Ω , T_j = 175°C Inductive load 0.01 0 10 20 30 40 50 60 Collector Current : I_C [A]



•Electrical Characteristic Curves

Fig.21 Typical IGBT Transient Thermal Impedance



●Inductive Load Switching Circuit and Waveform

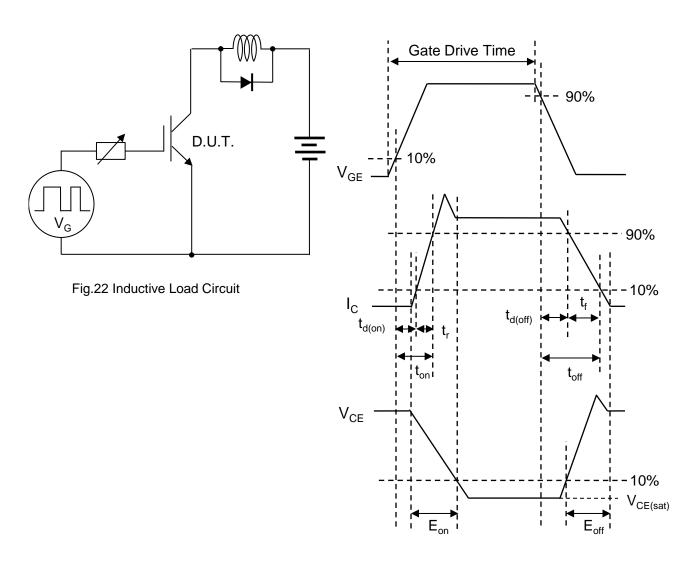


Fig.23 Inductive Load Waveform

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